

L Number	Hits	Search Text	DB	Time stamp
-	1346	(257/401).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 09:43
-	38	((257/401).CCLS.) and LDMOS	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 09:11
-	82	((257/401).CCLS.) and (lateral adj2 (MOS MOSFET) LDMOS)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 09:11
-	420	(257/342).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 09:11
-	142	(lateral adj2 (DMOS MOSFET MOS) LDMOS) and hot adj (electron hole carrier)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 09:12
-	120	(lateral adj2 (MOSFET MOS) LDMOS) and hot adj (electron hole carrier)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 09:12
-	56	((257/401).CCLS.) and (lateral adj2 (DMOS MOS MOSFET) LDMOS)) not (((257/401).CCLS.) and LDMOS and power) ((lateral adj2 (MOSFET MOS) LDMOS) and hot adj (electron hole carrier)))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 09:12
-	450	(257/204).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 09:12
-	79	LDMOS and hot adj (electron hole carrier)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 09:12
-	35	((257/401).CCLS.) and LDMOS and power	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 09:12
-	3	((257/401).CCLS.) and LDMOS) not (((257/401).CCLS.) and LDMOS and power)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 14:40
-	356	(257/343).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 09:13
-	366	((257/342).CCLS.) not ((257/343).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 09:13
-	5	((257/204).CCLS.) and (LDMOS lateral adj2 (DMOS MOS MOSFET))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 09:19
-	132	((257/341).CCLS.) and (LDMOS lateral adj2 (DMOS MOS MOSFET))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 10:53
-	290	((257/401).CCLS.) and array and drain	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 09:47
-	773	(257/409).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 09:47

-	84	((257/409).CCLS.) and (LDMOS lateral adj2 (DMOS MOS MOSFET))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 09:48
-	3	(douglas near3 brisbin).in.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 10:16
-	4	(david near3 tsuei).in.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 10:17
-	22	(alexander near3 owens).in.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 10:45
-	5	(andy near3 strachan).in.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 10:53
-	7	((257/776).CCLS.) and (LDMOS lateral adj2 (DMOS MOS MOSFET))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 10:54
-	674	(257/776).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 10:56
-	812	(257/341).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/15 11:54